DISCRETE SEMICONDUCTORS



Product specification

October 2018



Product specification

Rectifier diodes ultrafast

SYMBOL

Low forward volt drop

Fast switching

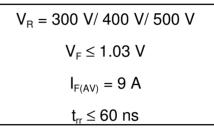
FEATURES

- Soft recovery characteristic
- High thermal cycling performance
- · Isolated mounting tab

K — — — A 001aaa020

BYV29F, BYV29X series

QUICK REFERENCE DATA



GENERAL DESCRIPTION

cathode (k)

anode (a) isolated

Ultra-fast epitaxial rectifier diodes intended for use in switched mode power supply output rectification, electronic lighting ballasts and high frequency switching circuits in general.

The BYV29F series is supplied in the SOD100 package. The BYV29X series is supplied in the SOD113 package.

PINNING

PIN

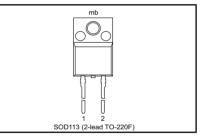
1

2

tab

DESCRIPTION

SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	. MAX.		UNIT	
		BYV29F/BYV29X		-300	-400	-500	
V _{RRM} V _R	Peak repetitive reverse voltage Continuous reverse voltage	$T_{hs} \leq 138^{\circ}C^{1}$	-	300 300	400 400	500 500	V
I _{F(AV)}	Average forward current ²	square wave; δ = 0.5; T _{hs} ≤ 90 °C	-		9		A
I _{FSM}	Non-repetitive peak forward	t = 10 ms	-		100		Α
	current	t = 8.3 ms sinusoidal; with reapplied	-		110		A
T _{stg}	Storage temperature Operating junction temperature	V _{RRM(max)}	-40		150 150		Ĵ.

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¹ T_{hs} de-rating for thermal stability.

² Neglecting switching and reverse current losses

Rectifier diodes ultrafast

BYV29F, BYV29X series

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Peak isolation voltage from all terminals to external heatsink	SOD100 package; R.H. \leq 65%; clean and dustfree	-	-	1500	V
V _{isol}	R.M.S. isolation voltage from all terminals to external heatsink	SOD113 package; f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65%; clean and dustfree	-	-	2500	V
C _{isol}	Capacitance from pin 2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs} R _{th j-a}	heatsink	with heatsink compound without heatsink compound in free air.		- - 55	5.5 7.2 -	K/W K/W K/W

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	I _F = 8 A; T _i = 150°C	-	0.90	1.03	V
		$ I_{r} = 8 \text{ A}$	-	1.05	1.25	V
		$l_{\rm F} = 20 {\rm A}$	-	1.20	1.40	V
I _R	Reverse current	$\dot{V}_{R} = V_{RRM}$	-	2.0	50	μA
		$V_{\rm R} = V_{\rm RRM}; T_{\rm i} = 100 \ ^{\circ}{\rm C}$	-	0.1	0.35	mA
Q _s	Reverse recovery charge	$V_{R}^{T} = V_{RRM}^{T}$; $T_{j} = 100 \degree C$ $I_{F} = 2 \ A \ to \ V_{R} \ge 30 \ V$;	-	40	60	nC
-		$dI_{F}/dt = 20 A/\mu s$				
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	50	60	ns
		dI _F /dt = 100 A/μs				
I _{rrm}	Peak reverse recovery current	$I_{\rm F} = 10 \text{ A to } V_{\rm R} \ge 30 \text{ V};$	-	4.0	5.5	A
		$dI_{F}/dt = 50 A/\mu s; T_{i} = 100^{\circ}C$				
V _{fr}	Forward recovery voltage	$I_{F} = 10 \text{ A}; dI_{F}/dt = 10 \text{ A}/\mu \text{s}$	-	2.5	-	V

BYV29F, BYV29X series

Rectifier diodes ultrafast

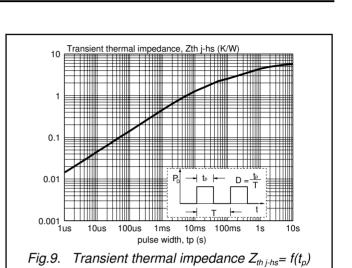
Ths(max) / C dl <u>F</u> PF / W 12 '_F Vo = 0.89V Rs = 0.019 Oh a = 1.57 dt 10 95 1.9 2.2 106 8 2.8 4 time 6 117 4 128 Q 100% 10% s 139 2 I R l rrm ۲ 0 ⊾ 150 4 IF(AV) / A 6 2 8 10 Fig.4. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = formfactor = $I_{F(RMS)} / I_{F(AV)}$. Fig.1. Definition of t_{rr} , Q_s and I_{rrm} trr / ns F 1000 IF=10 A 100 1A 🖉 time $^{\sf V}_{\sf F}$ 10 V _{fr} Tj = 25 C Tj = 100C ۷_F 1 10 dIF/dt (A/us) 100 time Fig.5. Maximum t_{rr} at $T_i = 25^{\circ}C$ and $100^{\circ}C$ Fig.2. Definition of V_{tr} Ths(max) / C 67.5 15 PF / W Irrm / A 10 Vo = 0.8900 V Rs = 0.0190 Ohms D = 1.0 IF=10A 0.5 1 10 95 IF=1A 0.2 0 1 0.1 122.5 5 t₀ T D = Tj = 25 C $T_{i} = 100C$ Т 0.01 ____150 15 0 10 -dIF/dt (A/us) 100 5 10 0 IF(AV) / A Fig.3. Maximum forward dissipation $P_F = f(I_{F(AV)})$; square wave where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$. Fig.6. Maximum I_{rrm} at $T_j = 25^{\circ}C$ and $100^{\circ}C$.

BYV29F, BYV29X series

Rectifier diodes ultrafast

30 150°C Ti °C 20 typ max 10 0 Ó 0.5 1.5 1 VF/V 2 Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j Qs / nC 1000 IF = 10 / 100 10 1 ∟ 1.0 10 -dIF/dt (A/us) 100

Fig.8. Maximum Q_s at $T_j = 25^{\circ}C$

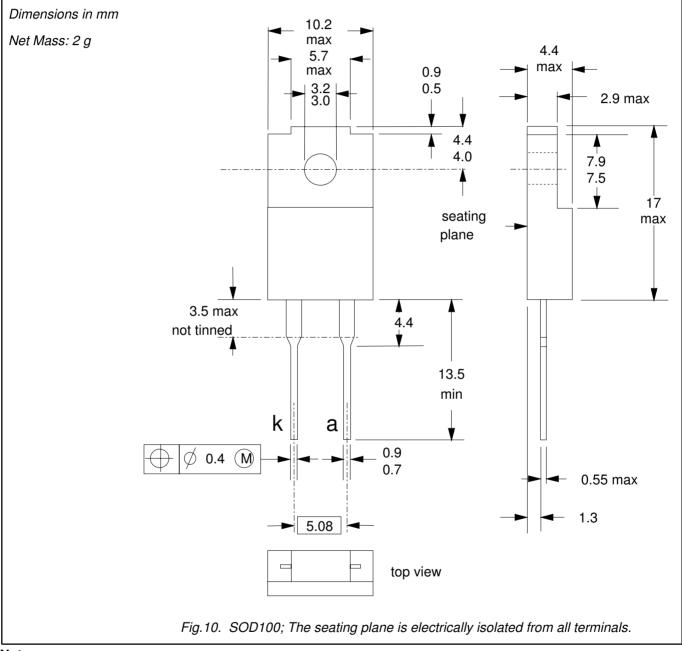




Rectifier diodes ultrafast

BYV29F, BYV29X series

MECHANICAL DATA





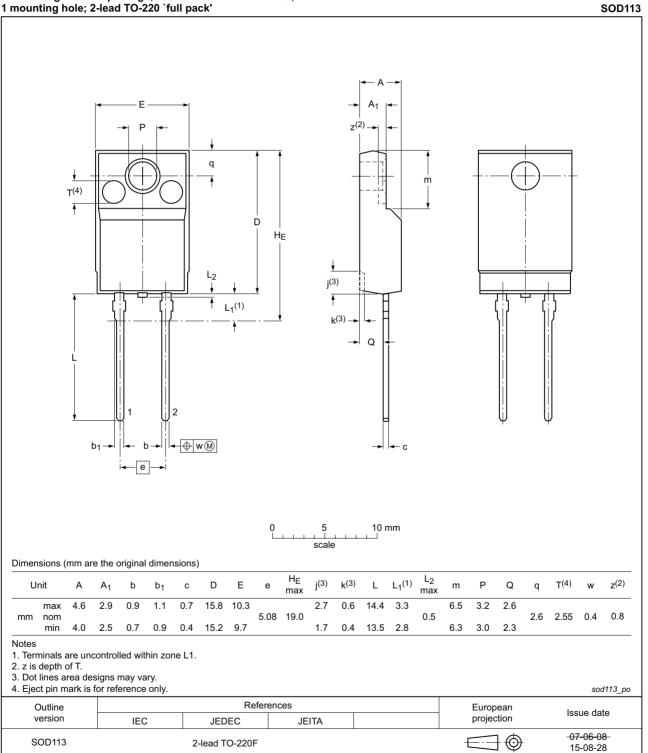
Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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MECHANICAL DATA

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 `full pack'



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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